

Heterojunction Bipolar Transistor Technology (InGaP HBT)

Broadband High Linearity Amplifier

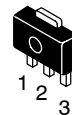
The MMG3013NT1 is a General Purpose Amplifier that is internally input matched and internally output matched. It is designed for a broad range of Class A, small-signal, high linearity, general purpose applications. It is suitable for applications with frequencies from 0 to 6000 MHz such as Cellular, PCS, BWA, WLL, PHS, CATV, VHF, UHF, UMTS and general small-signal RF.

Features

- Frequency: 0-6000 MHz
- P1dB: 20.5 dBm @ 900 MHz
- Small-Signal Gain: 20 dB @ 900 MHz
- Third Order Output Intercept Point: 36 dBm @ 900 MHz
- Single 5 Volt Supply
- Internally Matched to 50 Ohms
- Low Cost SOT-89 Surface Mount Package
- RoHS Compliant
- In Tape and Reel. T1 Suffix = 1000 Units per 12 mm, 7 inch Reel.

MMG3013NT1

**0-6000 MHz, 20 dB
20.5 dBm
InGaP HBT**



**CASE 1514-02, STYLE 1
SOT-89
PLASTIC**

Table 1. Typical Performance (1)

Characteristic	Symbol	900 MHz	2140 MHz	3500 MHz	Unit
Small-Signal Gain (S21)	G_p	20	17	14.5	dB
Input Return Loss (S11)	IRL	-17	-19	-15	dB
Output Return Loss (S22)	ORL	-11	-9	-12	dB
Power Output @1dB Compression	P1db	20.5	20.5	19	dBm
Third Order Output Intercept Point	IP3	36	34	32	dBm

1. $V_{CC} = 5$ Vdc, $T_C = 25^\circ\text{C}$, 50 ohm system

Table 2. Maximum Ratings

Rating	Symbol	Value	Unit
Supply Voltage (2)	V_{CC}	7	V
Supply Current (2)	I_{CC}	300	mA
RF Input Power	P_{in}	12	dBm
Storage Temperature Range	T_{stg}	-65 to +150	$^\circ\text{C}$
Junction Temperature (3)	T_J	150	$^\circ\text{C}$

2. Continuous voltage and current applied to device.

3. For reliable operation, the junction temperature should not exceed 150°C .

Table 3. Thermal Characteristics ($V_{CC} = 5$ Vdc, $I_{CC} = 90$ mA, $T_C = 25^\circ\text{C}$)

Characteristic	Symbol	Value (4)	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	42	$^\circ\text{C}/\text{W}$

4. Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf>. Select Documentation/Application Notes - AN1955.

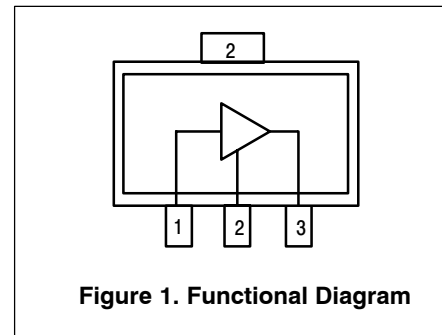
Table 4. Electrical Characteristics ($V_{CC} = 5$ Vdc, 900 MHz, $T_C = 25^\circ\text{C}$, 50 ohm system, in Freescale Application Circuit)

Characteristic		Symbol	Min	Typ	Max	Unit
Small-Signal Gain (S21)	900 MHz 2140 MHz	G_p	19.3 16	20 17	— —	dB
Input Return Loss (S11)		IRL	—	-17	—	dB
Output Return Loss (S22)		ORL	—	-11	—	dB
Power Output @ 1dB Compression		P1dB	—	20.5	—	dBm
Third Order Output Intercept Point		IP3	—	36	—	dBm
Noise Figure		NF	—	4	—	dB
Supply Current (1)		I_{CC}	80	90	110	mA
Supply Voltage (1)		V_{CC}	—	5	—	V

1. For reliable operation, the junction temperature should not exceed 150°C .

Table 5. Functional Pin Description

Pin Number	Pin Function
1	RF _{in}
2	Ground
3	RF _{out} /DC Supply

**Table 6. ESD Protection Characteristics**

Test Methodology	Class
Human Body Model (per JESD 22-A114)	1A (Minimum)
Machine Model (per EIA/JESD 22-A115)	A (Minimum)
Charge Device Model (per JESD 22-C101)	IV (Minimum)

Table 7. Moisture Sensitivity Level

Test Methodology	Rating	Package Peak Temperature	Unit
Per JESD 22-A113, IPC/JEDEC J-STD-020	1	260	°C

50 OHM TYPICAL CHARACTERISTICS

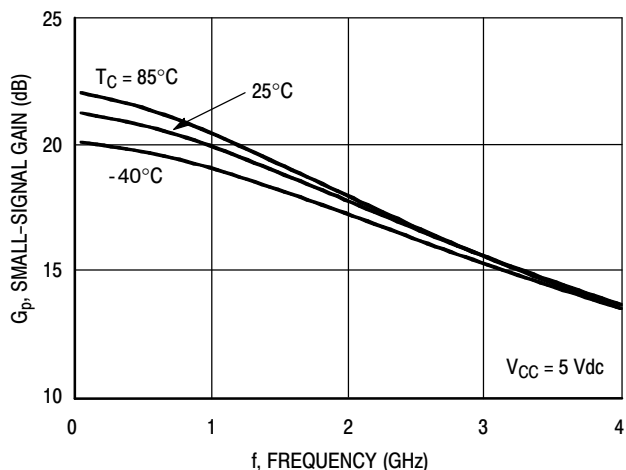


Figure 2. Small-Signal Gain (S21) versus Frequency

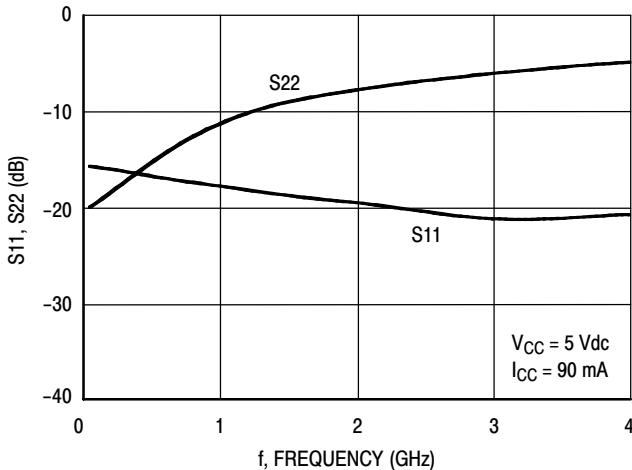


Figure 3. Input/Output Return Loss versus Frequency

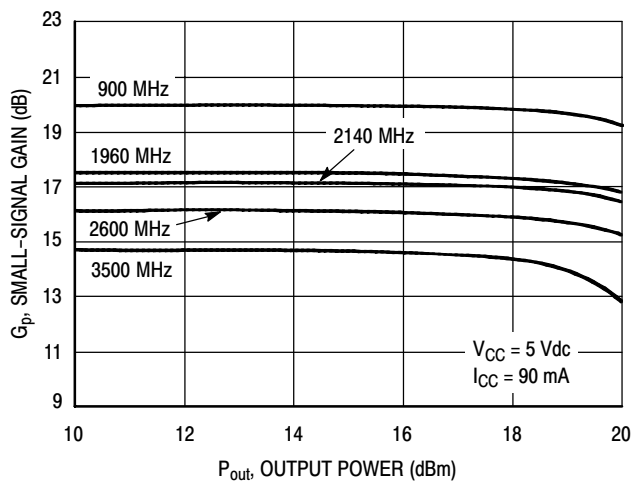


Figure 4. Small-Signal Gain versus Output Power

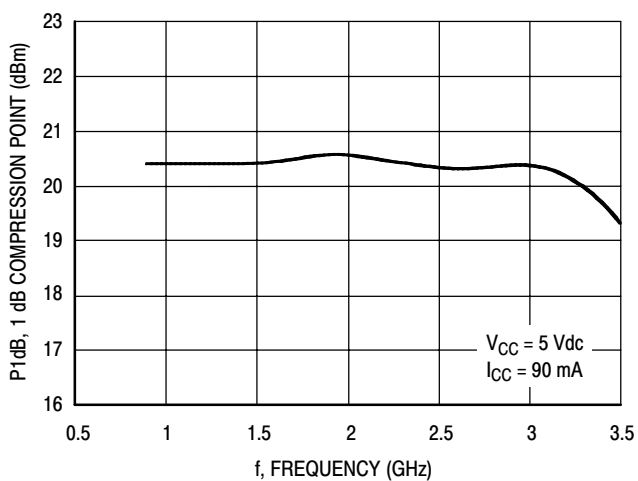


Figure 5. P1dB versus Frequency

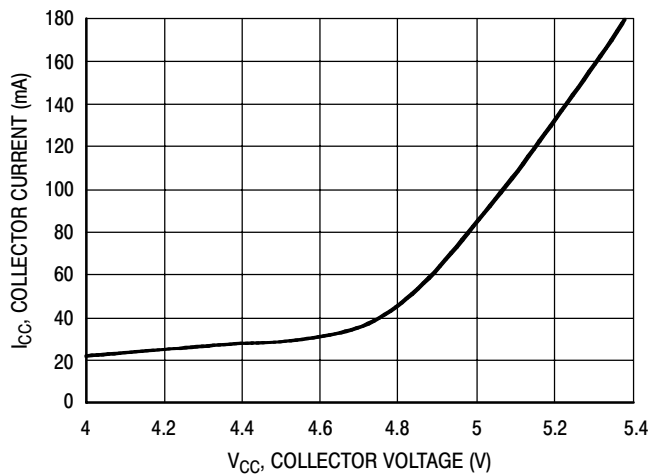


Figure 6. Collector Current versus Collector Voltage

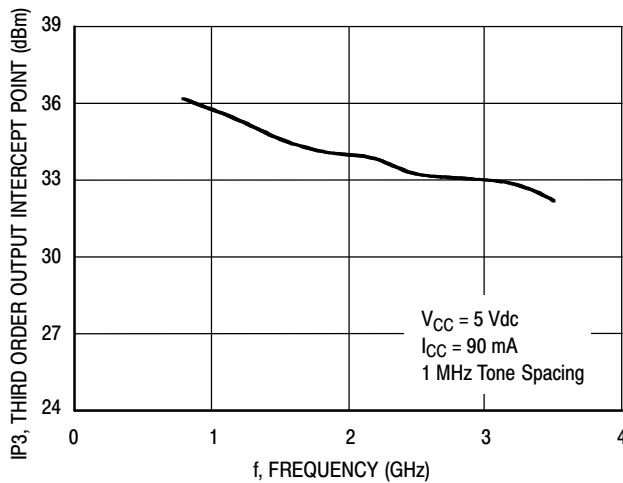


Figure 7. Third Order Output Intercept Point versus Frequency

50 OHM TYPICAL CHARACTERISTICS

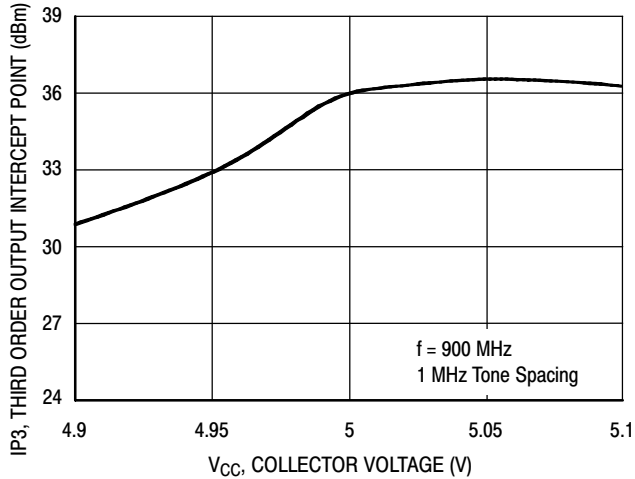


Figure 8. Third Order Output Intercept Point versus Collector Voltage

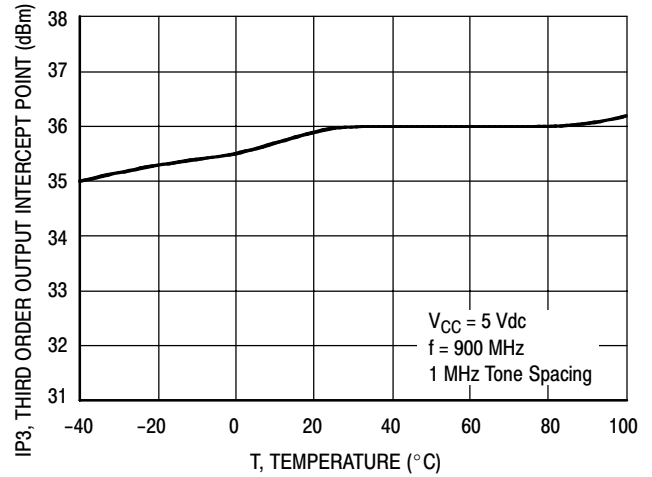


Figure 9. Third Order Output Intercept Point versus Case Temperature

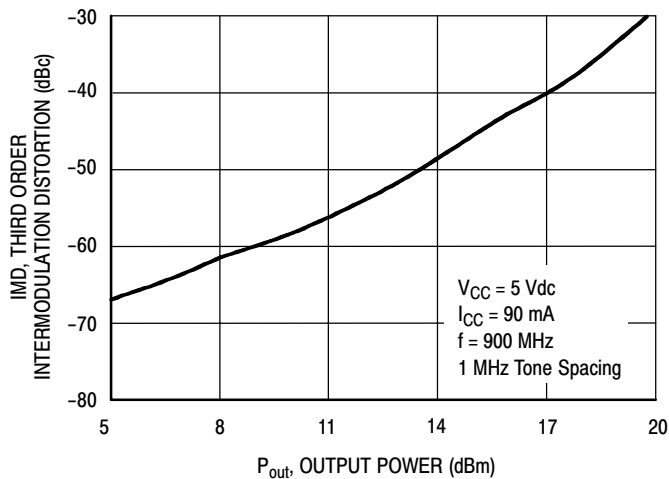
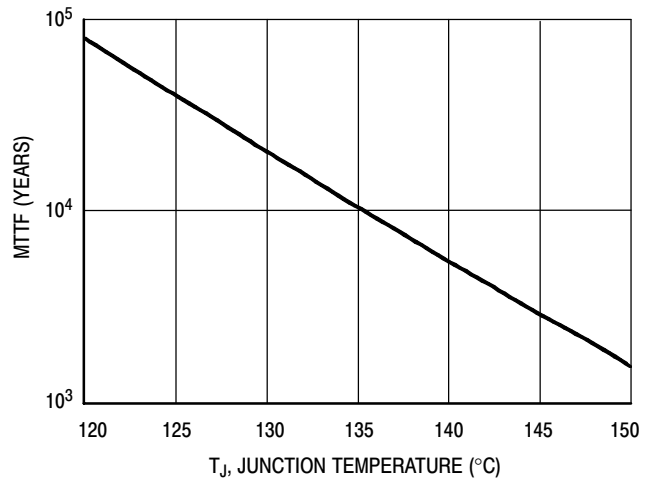


Figure 10. Third Order Intermodulation versus Output Power



NOTE: The MTTF is calculated with $V_{CC} = 5 \text{ Vdc}$, $I_{CC} = 90 \text{ mA}$

Figure 11. MTTF versus Junction Temperature

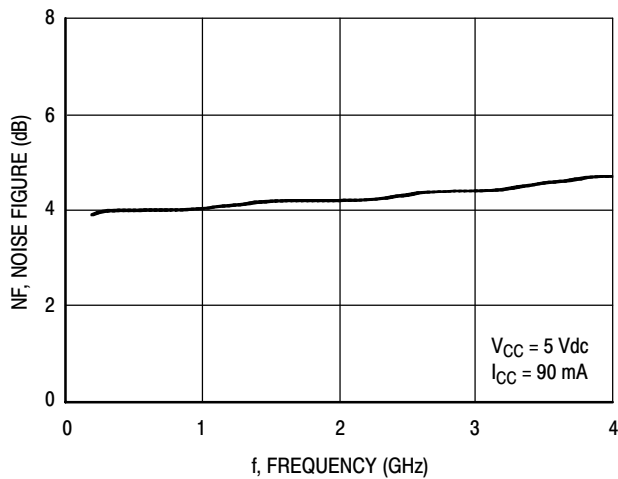


Figure 12. Noise Figure versus Frequency

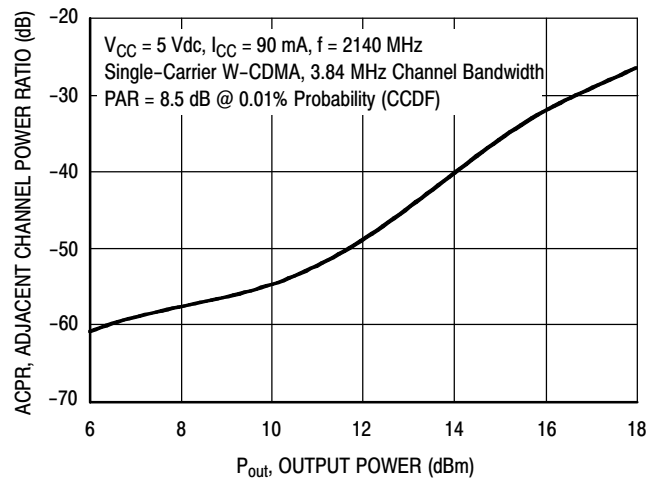


Figure 13. Single-Carrier W-CDMA Adjacent Channel Power Ratio versus Output Power

MMG3013NT1

50 OHM APPLICATION CIRCUIT: 40-800 MHz

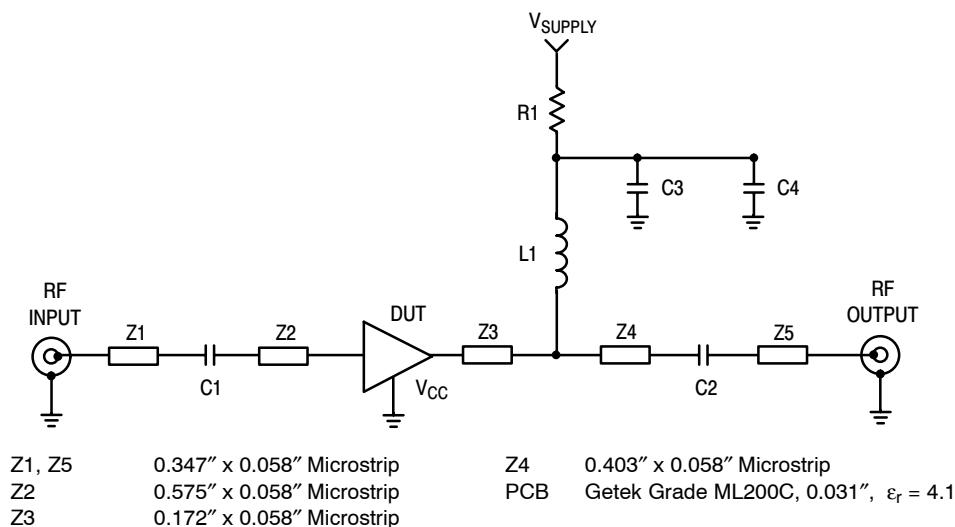


Figure 14. 50 Ohm Test Circuit Schematic

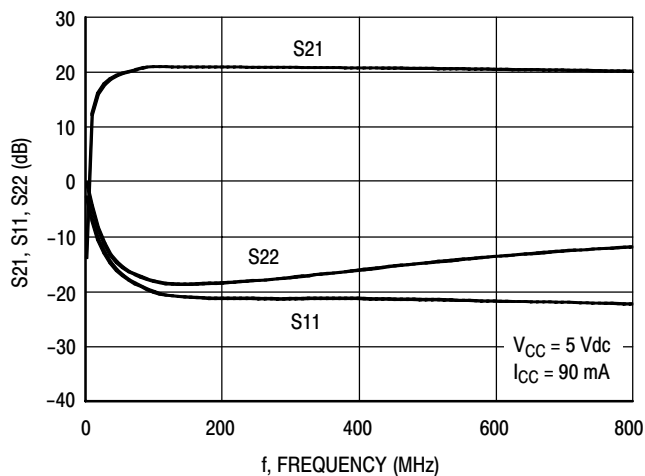


Figure 15. S21, S11 and S22 versus Frequency

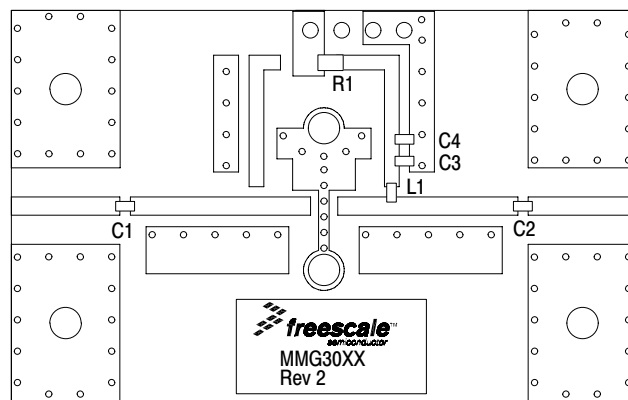


Figure 16. 50 Ohm Test Circuit Component Layout

Table 8. 50 Ohm Test Circuit Component Designations and Values

Part	Description	Part Number	Manufacturer
C1, C2	0.01 μ F Chip Capacitors	C0603C103J5RAC	Kemet
C3	0.1 μ F Chip Capacitor	C0603C104J5RAC	Kemet
C4	1 μ F Chip Capacitor	C0603C105J5RAC	Kemet
L1	470 nH Chip Inductor	BK2125HM471 - T	Taiyo Yuden
R1	0 Ω Chip Resistor	ERJ3GEY0R00V	Panasonic

50 OHM APPLICATION CIRCUIT: 800-3600 MHz

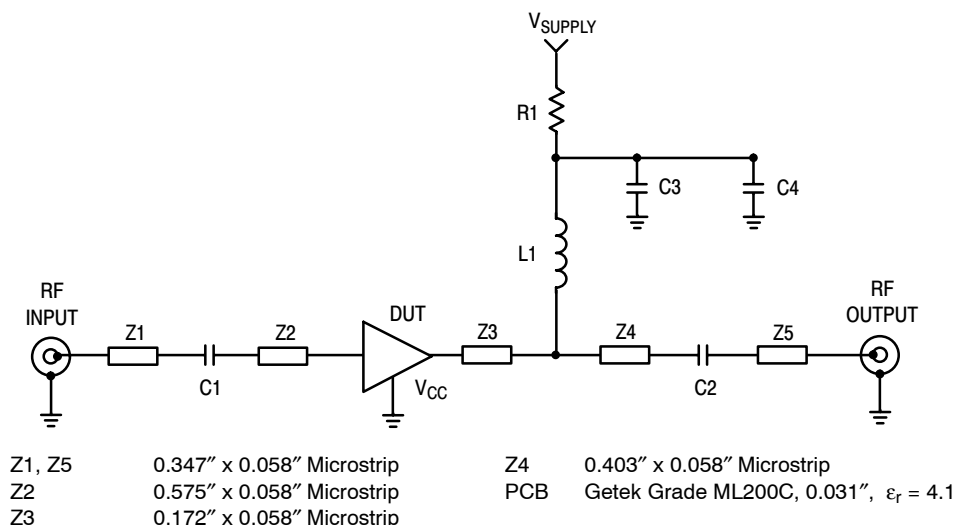


Figure 17. 50 Ohm Test Circuit Schematic

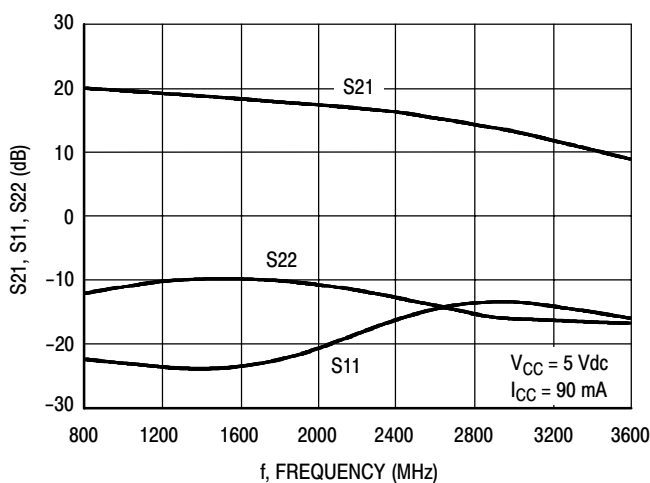


Figure 18. S21, S11 and S22 versus Frequency

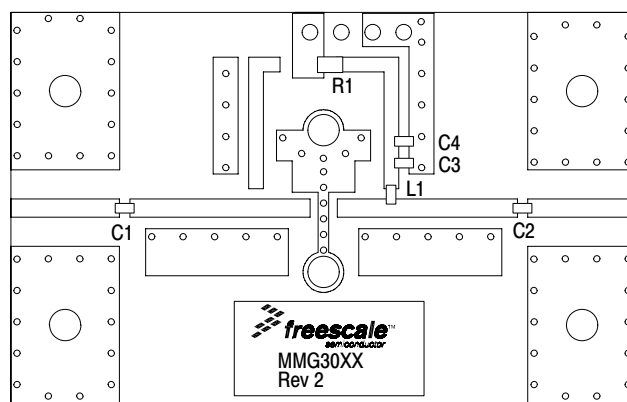


Figure 19. 50 Ohm Test Circuit Component Layout

Table 9. 50 Ohm Test Circuit Component Designations and Values

Part	Description	Part Number	Manufacturer
C1, C2	150 pF Chip Capacitors	C0603C151J5RAC	Kemet
C3	0.1 μ F Chip Capacitor	C0603C104J5RAC	Kemet
C4	1 μ F Chip Capacitor	C0603C105J5RAC	Kemet
L1	56 nH Chip Inductor	HK160856NJ-T	Taiyo Yuden
R1	0 Ω Chip Resistor	ERJ3GEY0R00V	Panasonic

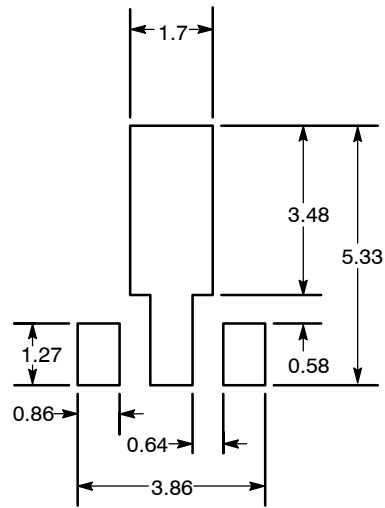
50 OHM TYPICAL CHARACTERISTICS

Table 10. Class A Common Emitter S-Parameters at $V_{CC} = 5 \text{ Vdc}$, $I_{CC} = 90 \text{ mA}$, $T_C = 25^\circ\text{C}$

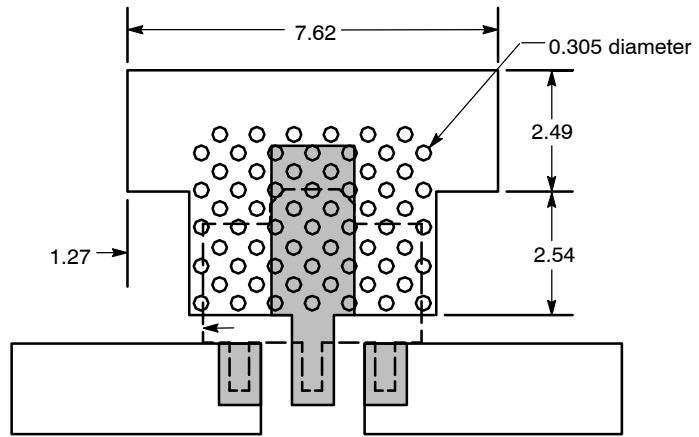
f GHz	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
	S ₁₁	∠φ	S ₂₁	∠φ	S ₁₂	∠φ	S ₂₂	∠φ
0.1	0.162717	171.108	11.479238	174.775	0.069393	-1.296	0.106264	-133.221
0.15	0.160561	167.971	11.415032	171.459	0.069131	-1.887	0.112247	-134.322
0.2	0.160153	163.027	11.337210	168.606	0.068870	-2.702	0.118610	-135.449
0.25	0.157910	159.994	11.263950	165.874	0.068640	-3.308	0.127240	-136.522
0.3	0.155640	156.091	11.200930	163.101	0.068460	-3.908	0.134977	-137.648
0.35	0.152870	152.178	11.160790	160.282	0.068400	-4.523	0.144410	-138.763
0.4	0.150710	148.189	11.096270	157.597	0.068380	-5.134	0.154090	-139.895
0.45	0.148730	144.135	11.027770	154.845	0.068210	-5.794	0.164250	-140.998
0.5	0.145840	140.465	10.957540	152.097	0.068260	-6.391	0.174550	-142.085
0.55	0.143950	136.404	10.876040	149.449	0.068090	-6.918	0.185240	-143.132
0.6	0.141980	132.557	10.785240	146.811	0.068040	-7.57	0.195510	-144.211
0.65	0.140120	128.67	10.695820	144.176	0.068000	-8.199	0.206040	-145.338
0.7	0.138450	124.924	10.604510	141.59	0.067790	-8.743	0.216910	-146.461
0.75	0.137510	121.228	10.504830	139.003	0.067690	-9.285	0.227810	-147.659
0.8	0.136570	117.62	10.400340	136.446	0.067590	-9.831	0.238140	-148.902
0.85	0.134433	114.245	10.295550	133.89	0.067520	-10.415	0.248290	-150.118
0.9	0.132707	110.998	10.186390	131.409	0.067420	-10.866	0.258400	-151.55
0.95	0.131087	107.842	10.073620	128.963	0.067380	-11.449	0.268360	-153.097
1	0.129567	104.859	9.965510	126.525	0.067220	-11.901	0.277810	-154.786
1.05	0.128275	102.209	9.842290	124.132	0.067050	-12.399	0.287510	-156.435
1.1	0.127137	99.637	9.725320	121.744	0.066970	-12.949	0.297010	-158.367
1.15	0.125513	97.509	9.610100	119.381	0.066930	-13.483	0.306110	-160.411
1.2	0.124020	95.409	9.485500	117.045	0.066790	-13.882	0.314950	-162.397
1.25	0.122379	93.482	9.367530	114.76	0.066840	-14.46	0.323700	-164.386
1.3	0.121234	91.761	9.251560	112.507	0.066710	-14.928	0.332570	-166.443
1.35	0.120081	90.16	9.129800	110.251	0.066685	-15.375	0.339940	-168.554
1.4	0.118817	88.664	9.011610	108.055	0.066670	-15.818	0.348650	-170.582
1.45	0.116609	87.326	8.892430	105.876	0.066687	-16.365	0.356290	-172.695
1.5	0.115374	86.23	8.772640	103.703	0.066764	-16.815	0.360061	-174.724
1.55	0.113850	80.021	8.708890	101.399	0.066970	-17.493	0.364627	-177.374
1.6	0.113120	77.212	8.598320	99.278	0.067057	-17.963	0.369410	-179.169
1.65	0.112080	75.253	8.485180	97.137	0.067090	-18.477	0.374600	179.129
1.7	0.111350	72.833	8.379040	95.075	0.067170	-18.984	0.380650	177.406
1.75	0.110660	70.651	8.273700	93.021	0.067200	-19.462	0.386070	175.7
1.8	0.110070	68.704	8.167240	90.99	0.067260	-19.938	0.391590	174.044
1.85	0.109570	66.752	8.063390	88.942	0.067320	-20.42	0.396600	172.328
1.9	0.108940	64.808	7.958390	86.97	0.067420	-20.891	0.402290	170.798
1.95	0.107610	63.28	7.856150	84.972	0.067460	-21.389	0.407630	169.234
2	0.106800	61.916	7.751440	83.012	0.067560	-21.917	0.412720	167.75
2.05	0.106240	60.415	7.651320	81.047	0.067600	-22.347	0.418620	166.176
2.1	0.104410	59.082	7.553170	79.114	0.067810	-22.888	0.423200	164.723
2.15	0.103200	57.787	7.452840	77.223	0.067960	-23.444	0.428690	163.19
2.2	0.102820	56.94	7.354920	75.325	0.067980	-23.91	0.433410	161.75
2.25	0.101220	55.6	7.259510	73.436	0.068230	-24.487	0.438440	160.241
2.3	0.100260	54.54	7.163530	71.577	0.068190	-24.984	0.442830	158.869
2.35	0.098910	53.312	7.072340	69.734	0.068480	-25.485	0.447010	157.463

Table 10. Class A Common Emitter S-Parameters at $V_{CC} = 5$ Vdc, $I_{CC} = 90$ mA, $T_C = 25^\circ\text{C}$ (continued)

f GHz	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
	S ₁₁	∠φ	S ₂₁	∠φ	S ₁₂	∠φ	S ₂₂	∠φ
2.4	0.097870	52.576	6.980770	67.882	0.068550	-26.108	0.451420	155.974
2.45	0.096530	51.814	6.892310	66.059	0.068780	-26.694	0.457800	154.6
2.5	0.095360	50.69	6.802480	64.259	0.068940	-27.154	0.460110	153.074
2.55	0.094140	49.939	6.719330	62.461	0.069120	-27.644	0.464930	151.617
2.6	0.093150	49.177	6.634260	60.65	0.069290	-28.295	0.469350	150.014
2.65	0.092180	48.019	6.554070	58.859	0.069490	-28.971	0.473140	148.442
2.7	0.091130	47.141	6.471630	57.062	0.069610	-29.561	0.477010	146.825
2.75	0.090470	46.394	6.392370	55.299	0.069850	-30.111	0.481850	145.214
2.8	0.089850	45.454	6.314980	53.505	0.070210	-30.649	0.485260	143.56
2.85	0.088790	44.657	6.238550	51.724	0.070340	-31.402	0.489440	141.782
2.9	0.088180	44.083	6.166300	50.021	0.070550	-32.044	0.494180	140.078
2.95	0.087640	43.291	6.088480	48.207	0.070750	-32.738	0.497180	138.23
3	0.086490	42.549	6.020040	46.489	0.071030	-33.388	0.501590	136.357
3.05	0.087170	42.041	5.950380	44.764	0.071280	-34.097	0.505070	134.738
3.1	0.086660	41.37	5.881680	43.022	0.071610	-34.666	0.509400	132.754
3.15	0.086130	41.387	5.814190	41.268	0.071920	-35.528	0.514040	130.875
3.2	0.086330	41.301	5.749680	39.547	0.072150	-36.302	0.518490	128.954
3.25	0.086760	41.239	5.684930	37.829	0.072340	-36.943	0.523620	126.955
3.3	0.086510	41.638	5.619060	36.098	0.072640	-37.799	0.525880	124.995
3.35	0.086820	41.81	5.557890	34.368	0.072800	-38.546	0.530230	123.081
3.4	0.087230	42.12	5.498110	32.629	0.073130	-39.319	0.534740	121.057
3.45	0.087680	42.727	5.437290	30.936	0.073490	-40.144	0.538080	119.195
3.5	0.087990	43.424	5.376810	29.22	0.073710	-40.92	0.542580	117.253
3.55	0.088730	44.082	5.319060	27.529	0.073970	-41.673	0.546650	115.36
3.6	0.089200	45.12	5.259990	25.838	0.074200	-42.467	0.550400	113.481



Recommended Solder Stencil

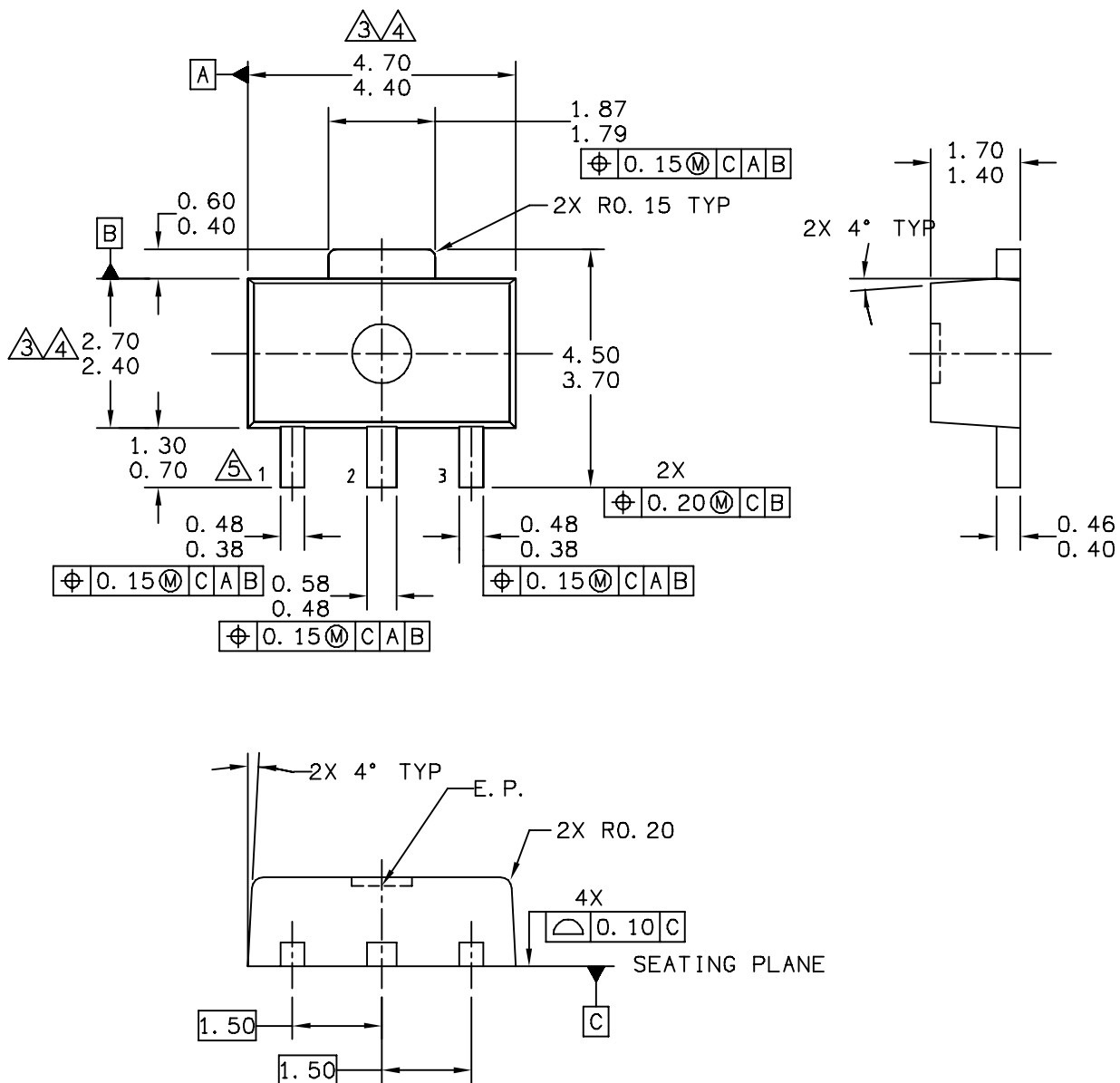


NOTES:

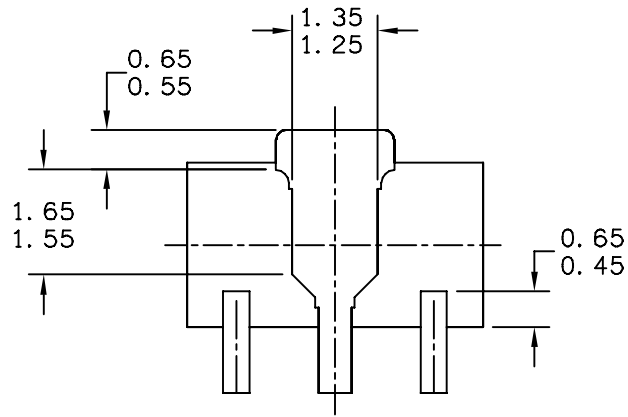
1. THERMAL AND RF GROUNDING CONSIDERATIONS SHOULD BE USED IN PCB LAYOUT DESIGN.
2. DEPENDING ON PCB DESIGN RULES, AS MANY VIAS AS POSSIBLE SHOULD BE PLACED ON THE LANDING PATTERN.
3. IF VIAS CANNOT BE PLACED ON THE LANDING PATTERN, THEN AS MANY VIAS AS POSSIBLE SHOULD BE PLACED AS CLOSE TO THE LANDING PATTERN AS POSSIBLE FOR OPTIMAL THERMAL AND RF PERFORMANCE.
4. RECOMMENDED VIA PATTERN SHOWN HAS 0.381 x 0.762 MM PITCH.

Figure 20. Recommended Mounting Configuration

PACKAGE DIMENSIONS



© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE	PRINT VERSION NOT TO SCALE	
TITLE: SOT-89, 4 LEAD, 4.5 X 2.5 PKG, 1.5 MM PITCH	DOCUMENT NO: 98ASA10586D	REV: D	
	CASE NUMBER: 1514-02	27 JUN 2007	
	STANDARD: NON-JEDEC		



BOTTOM VIEW

CASE STYLE:

STYLE 1:
 PIN 1. RF INPUT
 PIN 2. GROUND
 PIN 3. RF OUTPUT

STYLE 2:
 PIN 1. GATE
 PIN 2. SOURCE
 PIN 3. DRAIN

© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE	PRINT VERSION NOT TO SCALE	
TITLE: SOT-89, 4 LEAD, 4.5 X 2.5 PKG, 1.5 MM PITCH	DOCUMENT NO: 98ASA10586D	REV: D	
	CASE NUMBER: 1514-02	27 JUN 2007	
	STANDARD: NON-JEDEC		

NOTES:

1 DIMENSIONING AND TOLERANCING PER ASME Y14.5M – 1994.

2 ALL DIMENSIONS ARE IN MILLIMETERS.

3 DIMENSIONS DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.5mm PER END. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.5 mm PER SIDE.

4 DIMENSION ARE DETERMINED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

5 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

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TITLE: SOT-89, 4 LEAD, 4.5 X 2.5 PKG, 1.5 MM PITCH	DOCUMENT NO: 98ASA10586D	REV: D	
	CASE NUMBER: 1514-02	27 JUN 2007	
	STANDARD: NON-JEDEC		

PRODUCT DOCUMENTATION

Refer to the following documents to aid your design process.

Application Notes

- AN1955: Thermal Measurement Methodology of RF Power Amplifiers
- AN3100: General Purpose Amplifier Biasing

REVISION HISTORY

The following table summarizes revisions to this document.

Revision	Date	Description
4	Mar. 2007	<ul style="list-style-type: none">• Corrected and updated Part Numbers in Tables 8 and 9, Component Designations and Values, to RoHS compliant part numbers, p. 6, 7
5	July 2007	<ul style="list-style-type: none">• Replaced Case Outline 1514-01 with 1514-02, Issue D, p. 1, 11-13. Case updated to add missing dimension for Pin 1 and Pin 3.

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